

Welcome to E-XFL.COM

Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	1000
Number of Logic Elements/Cells	8000
Total RAM Bits	226304
Number of I/O	201
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FTBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lfxp2-8e-6ft256i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Figure 2-2. PFU Diagram



Slice

Slice 0 through Slice 2 contain two 4-input combinatorial Look-Up Tables (LUT4), which feed two registers. Slice 3 contains two LUT4s and no registers. For PFUs, Slice 0 and Slice 2 can also be configured as distributed memory, a capability not available in PFF blocks. Table 2-1 shows the capability of the slices in both PFF and PFU blocks along with the operation modes they enable. In addition, each PFU contains logic that allows the LUTs to be combined to perform functions such as LUT5, LUT6, LUT7 and LUT8. There is control logic to perform set/reset functions (programmable as synchronous/asynchronous), clock select, chip-select and wider RAM/ROM functions. Figure 2-3 shows an overview of the internal logic of the slice. The registers in the slice can be configured as positive/negative edge triggered or level sensitive clocks.

Table 2-1.	Resources	and Modes	Available	per Slice
			/ IT amaint	

	PFU E	BLock	PFF Block			
Slice	Resources	Modes	Resources	Modes		
Slice 0	2 LUT4s and 2 Registers	Logic, Ripple, RAM, ROM	2 LUT4s and 2 Registers	Logic, Ripple, ROM		
Slice 1	2 LUT4s and 2 Registers	Logic, Ripple, ROM	2 LUT4s and 2 Registers	Logic, Ripple, ROM		
Slice 2	2 LUT4s and 2 Registers	Logic, Ripple, RAM, ROM	2 LUT4s and 2 Registers	Logic, Ripple, ROM		
Slice 3	2 LUT4s	Logic, ROM	2 LUT4s	Logic, ROM		

Slice 0 through Slice 2 have 14 input signals: 13 signals from routing and one from the carry-chain (from the adjacent slice or PFU). There are seven outputs: six to routing and one to carry-chain (to the adjacent PFU). Slice 3 has 13 input signals from routing and four signals to routing. Table 2-2 lists the signals associated with Slice 0 to Slice 2.



Figure 2-5. Clock Divider Connections



Clock Distribution Network

LatticeXP2 devices have eight quadrant-based primary clocks and between six and eight flexible region-based secondary clocks/control signals. Two high performance edge clocks are available on each edge of the device to support high speed interfaces. The clock inputs are selected from external I/Os, the sysCLOCK PLLs, or routing. Clock inputs are fed throughout the chip via the primary, secondary and edge clock networks.

Primary Clock Sources

LatticeXP2 devices derive primary clocks from four sources: PLL outputs, CLKDIV outputs, dedicated clock inputs and routing. LatticeXP2 devices have two to four sysCLOCK PLLs, located in the four corners of the device. There are eight dedicated clock inputs, two on each side of the device. Figure 2-6 shows the primary clock sources.



Figure 2-12. Secondary Clock Selection



Slice Clock Selection

Figure 2-13 shows the clock selections and Figure 2-14 shows the control selections for Slice0 through Slice2. All the primary clocks and the four secondary clocks are routed to this clock selection mux. Other signals, via routing, can be used as clock inputs to the slices. Slice controls are generated from the secondary clocks or other signals connected via routing.

If none of the signals are selected for both clock and control, then the default value of the mux output is 1. Slice 3 does not have any registers; therefore it does not have the clock or control muxes.

Figure 2-13. Slice0 through Slice2 Clock Selection





register. Similarly, CE and RST are selected from their four respective sources (CE0, CE1, CE2, CE3 and RST0, RST1, RST2, RST3) at each input register, pipeline register and output register.

Signed and Unsigned with Different Widths

The DSP block supports other widths, in addition to x9, x18 and x36 widths, of signed and unsigned multipliers. For unsigned operands, unused upper data bits should be filled to create a valid x9, x18 or x36 operand. For signed two's complement operands, sign extension of the most significant bit should be performed until x9, x18 or x36 width is reached. Table 2-7 provides an example of this.

Table 2-7. Sign Extension Example

Number	Unsigned	Unsigned 9-bit	InsignedUnsignedTwo's Compleme9-bit18-bitSignedSigned 9 Bits		Two's Complement Signed 9 Bits	Two's Complement Signed 18 Bits
+5	0101	000000101	00000000000000101	0101	00000101	00000000000000101
-6	N/A	N/A	N/A	1010	111111010	1111111111111111010

OVERFLOW Flag from MAC

The sysDSP block provides an overflow output to indicate that the accumulator has overflowed. "Roll-over" occurs and an overflow signal is indicated when any of the following is true: two unsigned numbers are added and the result is a smaller number than the accumulator, two positive numbers are added with a negative sum or two negative numbers are added with a positive sum. Note that when overflow occurs the overflow flag is present for only one cycle. By counting these overflow pulses in FPGA logic, larger accumulators can be constructed. The conditions for the overflow signal for signed and unsigned operands are listed in Figure 2-24.

Figure 2-24. Accumulator Overflow/Underflow





IPexpress[™]

The user can access the sysDSP block via the Lattice IPexpress tool, which provides the option to configure each DSP module (or group of modules), or by direct HDL instantiation. In addition, Lattice has partnered with The Math-Works[®] to support instantiation in the Simulink[®] tool, a graphical simulation environment. Simulink works with Diamond to dramatically shorten the DSP design cycle in Lattice FPGAs.

Optimized DSP Functions

Lattice provides a library of optimized DSP IP functions. Some of the IP cores planned for the LatticeXP2 DSP include the Bit Correlator, FFT functions, FIR Filter, Reed-Solomon Encoder/Decoder, Turbo Encoder/Decoder and Convolutional Encoder/Decoder. Please contact Lattice to obtain the latest list of available DSP IP cores.

Resources Available in the LatticeXP2 Family

Table 2-8 shows the maximum number of multipliers for each member of the LatticeXP2 family. Table 2-9 shows the maximum available EBR RAM Blocks and Serial TAG Memory bits in each LatticeXP2 device. EBR blocks, together with Distributed RAM can be used to store variables locally for fast DSP operations.

Device	DSP Block	9x9 Multiplier	18x18 Multiplier	36x36 Multiplier
XP2-5	3	24	12	3
XP2-8	4	32	16	4
XP2-17	5	40	20	5
XP2-30	7	56	28	7
XP2-40	8	64	32	8

Table 2-8. Maximum Number of DSP Blocks in the LatticeXP2 Family

Table 2-9. Embedded SRAM/TAG Memor	v in the LatticeXP2 Family

Device	EBR SRAM Block	Total EBR SRAM (Kbits)	TAG Memory (Bits)
XP2-5	9	166	632
XP2-8	12	221	768
XP2-17	15	276	2184
XP2-30	21	387	2640
XP2-40	48	885	3384

LatticeXP2 DSP Performance

Table 2-10 lists the maximum performance in Millions of MAC (MMAC) operations per second for each member of the LatticeXP2 family.

Table 2-10. DSP Performance

Device	DSP Block	DSP Performance MMAC
XP2-5	3	3,900
XP2-8	4	5,200
XP2-17	5	6,500
XP2-30	7	9,100
XP2-40	8	10,400

For further information on the sysDSP block, please see TN1140, <u>LatticeXP2 sysDSP Usage Guide</u>.



Table 2-11. PIO Signal List

Name	Туре	Description
CE	Control from the core	Clock enables for input and output block flip-flops
CLK	Control from the core	System clocks for input and output blocks
ECLK1, ECLK2	Control from the core	Fast edge clocks
LSR	Control from the core	Local Set/Reset
GSRN	Control from routing	Global Set/Reset (active low)
INCK ²	Input to the core	Input to Primary Clock Network or PLL reference inputs
DQS	Input to PIO	DQS signal from logic (routing) to PIO
INDD	Input to the core	Unregistered data input to core
INFF	Input to the core	Registered input on positive edge of the clock (CLK0)
IPOS0, IPOS1	Input to the core	Double data rate registered inputs to the core
QPOS0 ¹ , QPOS1 ¹	Input to the core	Gearbox pipelined inputs to the core
QNEG0 ¹ , QNEG1 ¹	Input to the core	Gearbox pipelined inputs to the core
OPOS0, ONEG0, OPOS2, ONEG2	Output data from the core	Output signals from the core for SDR and DDR operation
OPOS1 ONEG1	Tristate control from the core	Signals to Tristate Register block for DDR operation
DEL[3:0]	Control from the core	Dynamic input delay control bits
TD	Tristate control from the core	Tristate signal from the core used in SDR operation
DDRCLKPOL	Control from clock polarity bus	Controls the polarity of the clock (CLK0) that feed the DDR input block
DQSXFER	Control from core	Controls signal to the Output block

1. Signals available on left/right/bottom only.

2. Selected I/O.

PIO

The PIO contains four blocks: an input register block, output register block, tristate register block and a control logic block. These blocks contain registers for operating in a variety of modes along with necessary clock and selection logic.

Input Register Block

The input register blocks for PIOs contain delay elements and registers that can be used to condition high-speed interface signals, such as DDR memory interfaces and source synchronous interfaces, before they are passed to the device core. Figure 2-26 shows the diagram of the input register block.

Input signals are fed from the sysIO buffer to the input register block (as signal DI). If desired, the input signal can bypass the register and delay elements and be used directly as a combinatorial signal (INDD), a clock (INCK) and, in selected blocks, the input to the DQS delay block. If an input delay is desired, designers can select either a fixed delay or a dynamic delay DEL[3:0]. The delay, if selected, reduces input register hold time requirements when using a global clock.

The input block allows three modes of operation. In the Single Data Rate (SDR) mode, the data is registered, by one of the registers in the SDR Sync register block, with the system clock. In DDR mode two registers are used to sample the data on the positive and negative edges of the DQS signal which creates two data streams, D0 and D2. D0 and D2 are synchronized with the system clock before entering the core. Further information on this topic can be found in the DDR Memory Support section of this data sheet.

By combining input blocks of the complementary PIOs and sharing registers from output blocks, a gearbox function can be implemented, that takes a double data rate signal applied to PIOA and converts it as four data streams, IPOS0A, IPOS1A, IPOS0B and IPOS1B. Figure 2-26 shows the diagram using this gearbox function. For more information on this topic, please see TN1138, LatticeXP2 High Speed I/O Interface.



DLL Calibrated DQS Delay Block

Source synchronous interfaces generally require the input clock to be adjusted in order to correctly capture data at the input register. For most interfaces a PLL is used for this adjustment. However, in DDR memories the clock, referred to as DQS, is not free-running, and this approach cannot be used. The DQS Delay block provides the required clock alignment for DDR memory interfaces.

The DQS signal (selected PIOs only, as shown in Figure 2-30) feeds from the PAD through a DQS delay element to a dedicated DQS routing resource. The DQS signal also feeds polarity control logic which controls the polarity of the clock to the sync registers in the input register blocks. Figure 2-30 and Figure 2-31 show how the DQS transition signals are routed to the PIOs.

The temperature, voltage and process variations of the DQS delay block are compensated by a set of 6-bit bus calibration signals from two dedicated DLLs (DDR_DLL) on opposite sides of the device. Each DLL compensates DQS delays in its half of the device as shown in Figure 2-30. The DLL loop is compensated for temperature, voltage and process variations by the system clock and feedback loop.



Figure 2-30. Edge Clock, DLL Calibration and DQS Local Bus Distribution



DQSXFER

LatticeXP2 devices provide a DQSXFER signal to the output buffer to assist it in data transfer to DDR memories that require DQS strobe be shifted 90°. This shifted DQS strobe is generated by the DQSDEL block. The DQSXFER signal runs the span of the data bus.

sysIO Buffer

Each I/O is associated with a flexible buffer referred to as a sysIO buffer. These buffers are arranged around the periphery of the device in groups referred to as banks. The sysIO buffers allow users to implement the wide variety of standards that are found in today's systems including LVCMOS, SSTL, HSTL, LVDS and LVPECL.

sysIO Buffer Banks

LatticeXP2 devices have eight sysIO buffer banks for user I/Os arranged two per side. Each bank is capable of supporting multiple I/O standards. Each sysIO bank has its own I/O supply voltage (V_{CCIO}). In addition, each bank has voltage references, V_{REF1} and V_{REF2} , that allow it to be completely independent from the others. Figure 2-32 shows the eight banks and their associated supplies.

In LatticeXP2 devices, single-ended output buffers and ratioed input buffers (LVTTL, LVCMOS and PCI) are powered using V_{CCIO} . LVTTL, LVCMOS33, LVCMOS25 and LVCMOS12 can also be set as fixed threshold inputs independent of V_{CCIO} .

Each bank can support up to two separate V_{REF} voltages, V_{REF1} and V_{REF2} , that set the threshold for the referenced input buffers. Some dedicated I/O pins in a bank can be configured to be a reference voltage supply pin. Each I/O is individually configurable based on the bank's supply and reference voltages.

тор

Figure 2-32. LatticeXP2 Banks



воттом



sysIO Recommended Operating Conditions

		V _{CCIO}		V _{REF} (V)			
Standard	Min.	Тур.	Max.	Min.	Тур.	Max.	
LVCMOS33 ²	3.135	3.3	3.465	—			
LVCMOS25 ²	2.375	2.5	2.625	—			
LVCMOS18	1.71	1.8	1.89	—	—	—	
LVCMOS15	1.425	1.5	1.575	—			
LVCMOS12 ²	1.14	1.2	1.26	—			
LVTTL33 ²	3.135	3.3	3.465	—	—	—	
PCI33	3.135	3.3	3.465	—			
SSTL18_I ² , SSTL18_II ²	1.71	1.8	1.89	0.833	0.9	0.969	
SSTL25_I ² , SSTL25_II ²	2.375	2.5	2.625	1.15	1.25	1.35	
SSTL33_I ² , SSTL33_II ²	3.135	3.3	3.465	1.3	1.5	1.7	
HSTL15_l ²	1.425	1.5	1.575	0.68	0.75	0.9	
HSTL18_I ² , HSTL18_II ²	1.71	1.8	1.89	0.816	0.9	1.08	
LVDS25 ²	2.375	2.5	2.625	—			
MLVDS251	2.375	2.5	2.625	—			
LVPECL33 ^{1, 2}	3.135	3.3	3.465	—			
BLVDS25 ^{1, 2}	2.375	2.5	2.625	—			
RSDS ^{1, 2}	2.375	2.5	2.625	—			
SSTL18D_I ² , SSTL18D_II ²	1.71	1.8	1.89	—	—	—	
SSTL25D_ I ² , SSTL25D_II ²	2.375	2.5	2.625	—	—	—	
SSTL33D_ I ² , SSTL33D_ II ²	3.135	3.3	3.465	—	—	—	
HSTL15D_ I ²	1.425	1.5	1.575	—	—	—	
HSTL18D_ I ² , HSTL18D_ II ²	1.71	1.8	1.89	_	—	—	

Over Recommended Operating Conditions

1. Inputs on chip. Outputs are implemented with the addition of external resistors. 2. Input on this standard does not depend on the value of V_{CCIO} .



sysIO Single-Ended DC Electrical Characteristics

Input/Output		V _{IL}	VII	1	V _{OL}	V _{OH}		
Standard	Min. (V)	Max. (V)	Min. (V)	Max. (V)	Max. (V)	Min. (V)	l _{OL} 1 (mA)	l _{OH} ¹ (mA)
LVCMOS33	-0.3	0.8	2.0	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4
					0.2	V _{CCIO} - 0.2	0.1	-0.1
LVTTL33	-0.3	0.8	2.0	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4
					0.2	V _{CCIO} - 0.2	0.1	-0.1
LVCMOS25	-0.3	0.7	1.7	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4
	0.2	0.2	V _{CCIO} - 0.2	0.1	-0.1			
LVCMOS18	-0.3	0.35 V _{CCIO}	0.65 V _{CCIO}	3.6	0.4	V _{CCIO} - 0.4	16, 12, 8, 4	-16, -12, -8, -4
					0.2	V _{CCIO} - 0.2	0.1	-0.1
	0.2	0.25 \/	0.65 \	2.6	0.4	V _{CCIO} - 0.4	8, 4	-8, -4
	-0.5	0.35 VCCIO	0.03 V CCIO	3.0	0.2	V _{CCIO} - 0.2	0.1	-0.1
	-0.3	0.35 V	0.65 V	3.6	0.4	V _{CCIO} - 0.4	6, 2	-6, -2
	-0.5	0.35 V _{CC}	0.05 V _{CC}	3.0	0.2	V _{CCIO} - 0.2	0.1	-0.1
PCI33	-0.3	0.3 V _{CCIO}	0.5 V _{CCIO}	3.6	0.1 V _{CCIO}	0.9 V _{CCIO}	1.5	-0.5
SSTL33_I	-0.3	V _{REF} - 0.2	V _{REF} + 0.2	3.6	0.7	V _{CCIO} - 1.1	8	-8
SSTL33_II	-0.3	V _{REF} - 0.2	V _{REF} + 0.2	3.6	0.5	V _{CCIO} - 0.9	16	-16
SSTI 25 J	-0.3	Vpcc - 0 18	Vp== ± 0.18	3.6	0.54	Vacua - 0.62	7.6	-7.6
001220_1	-0.0	VREF - 0.10	VREF + 0.10	0.0	0.04	ACCIO - 0.05	12	-12
SSTI 25 II	-0.3	V0 18	V+0 18	36	0.35	Vac: a 0.43	15.2	-15.2
001225_11	-0.0	VREF - 0.10	VREF + 0.10	0.0	0.00	ACCIO - 0.42	20	-20
SSTL18_I	-0.3	V _{REF} - 0.125	V _{REF} + 0.125	3.6	0.4	V _{CCIO} - 0.4	6.7	-6.7
	-0.3	V0 125	V ± 0 125	36	0.28	Vac 0.28	8	-8
001210_1	-0.0	VREF - 0.120	VREF + 0.120	0.0	0.20	VCCIO - 0.20	11	-11
HSTI 15 I	-0.3	Vpcc - 0 1		3.6	0.4		4	-4
	0.0	VREF 0.1	VREF 1 0.1	0.0	0.4	VCCID 0.4	8	-8
HSTI 18 I	-0.3	Vp== - 0 1		3.6	0.4		8	-8
	0.0	KEF - 0.1		0.0	U.T		12	-12
HSTL18_II	-0.3	V _{REF} - 0.1	V _{REF} + 0.1	3.6	0.4	V _{CCIO} - 0.4	16	-16

Over Recommended Operating Conditions

 The average DC current drawn by I/Os between GND connections, or between the last GND in an I/O bank and the end of an I/O bank, as shown in the logic signal connections table shall not exceed n * 8mA, where n is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.



BLVDS

The LatticeXP2 devices support the BLVDS standard. This standard is emulated using complementary LVCMOS outputs in conjunction with a parallel external resistor across the driver outputs. BLVDS is intended for use when multi-drop and bi-directional multi-point differential signaling is required. The scheme shown in Figure 3-2 is one possible solution for bi-directional multi-point differential signals.





Table 3-2. BLVDS DC Conditions¹

		Typical		
Parameter	Description	Ζο = 45 Ω	Ζο = 90 Ω	Units
V _{CCIO}	Output Driver Supply (+/- 5%)	2.50	2.50	V
Z _{OUT}	Driver Impedance	10.00	10.00	Ω
R _S	Driver Series Resistor (+/- 1%)	90.00	90.00	Ω
R _{TL}	Driver Parallel Resistor (+/- 1%)	45.00	90.00	Ω
R _{TR}	Receiver Termination (+/- 1%)	45.00	90.00	Ω
V _{OH}	Output High Voltage (After R _{TL})	1.38	1.48	V
V _{OL}	Output Low Voltage (After R _{TL})	1.12	1.02	V
V _{OD}	Output Differential Voltage (After R _{TL})	0.25	0.46	V
V _{CM}	Output Common Mode Voltage	1.25	1.25	V
I _{DC}	DC Output Current	11.24	10.20	mA

Over Recommended Operating Conditions

1. For input buffer, see LVDS table.



Register-to-Register Performance (Continued)

Function	-7 Timing	Units
DSP IP Functions		
16-Tap Fully-Parallel FIR Filter	198	MHz
1024-pt FFT	221	MHz
8X8 Matrix Multiplication	196	MHz

1. These timing numbers were generated using the ispLEVER design tool. Exact performance may vary with device, design and tool version. The tool uses internal parameters that have been characterized but are not tested on every device.

Derating Timing Tables

Logic timing provided in the following sections of this data sheet and the Diamond design tools are worst case numbers in the operating range. Actual delays at nominal temperature and voltage for best case process, can be much better than the values given in the tables. The Diamond design tool can provide logic timing numbers at a particular temperature and voltage.







Note: Input data and address are registered at the positive edge of the clock and output data appears after the positive edge of the clock.



sysCLOCK PLL Timing

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
f _{IN}	Input Clock Frequency (CLKI, CLKFB)		10		435	MHz
fouт	Output Clock Frequency (CLKOP, CLKOS)		10	_	435	MHz
f	K-Divider Output Frequency	CLKOK	0.078		217.5	MHz
'OUT2		CLKOK2	3.3		145	MHz
f _{VCO}	PLL VCO Frequency		435	_	870	MHz
f _{PFD}	Phase Detector Input Frequency		10		435	MHz
AC Characte	eristics					
t _{DT}	Output Clock Duty Cycle	Default duty cycle selected ³	45	50	55	%
t _{CPA}	Coarse Phase Adjust		-5	0	5	%
t _{PH} ⁴	Output Phase Accuracy		-5	0	5	%
		f _{OUT} > 400 MHz	—		±50	ps
t _{OPJIT} 1	Output Clock Period Jitter	100 MHz < f _{OUT} < 400 MHz	—	_	±125	ps
		f _{OUT} < 100 MHz	—	_	0.025	UIPP
t _{SK}	Input Clock to Output Clock Skew	N/M = integer	—		±240	ps
t _{OPW}	Output Clock Pulse Width	At 90% or 10%	1	_	—	ns
+ 2	PLL Look in Timo	25 to 435 MHz	—	_	50	μs
LOCK		10 to 25 MHz	_		100	μs
t _{IPJIT}	Input Clock Period Jitter		_		±200	ps
t _{FBKDLY}	External Feedback Delay		_		10	ns
t _{HI}	Input Clock High Time	90% to 90%	0.5	_	—	ns
t _{LO}	Input Clock Low Time	10% to 10%	0.5		_	ns
t _{RSTKW}	Reset Signal Pulse Width (RSTK)		10	—	—	ns
t _{RSTW}	Reset Signal Pulse Width (RST)		500	—	—	ns

Over Recommended Operating Conditions

1. Jitter sample is taken over 10,000 samples of the primary PLL output with clean reference clock.

2. Output clock is valid after t_{LOCK} for PLL reset and dynamic delay adjustment.

3. Using LVDS output buffers.

4. Relative to CLKOP.



FlashBAK Time (from EBR to Flash)

Over Recommended Operating Conditions

Device	EBR Density (Bits)	Time (Typ.)	Units
XP2-5	166K	1.5	S
XP2-8	221K	1.5	S
XP2-17	276K	1.5	S
XP2-30	387K	2.0	S
XP2-40	885K	3.0	S

JTAG Port Timing Specifications

Over Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Units
f _{MAX}	TCK Clock Frequency	—	25	MHz
t _{BTCP}	TCK [BSCAN] clock pulse width	40	—	ns
t _{BTCPH}	TCK [BSCAN] clock pulse width high	20	—	ns
t _{BTCPL}	TCK [BSCAN] clock pulse width low	20	—	ns
t _{BTS}	TCK [BSCAN] setup time	8	—	ns
t _{BTH}	TCK [BSCAN] hold time	10	—	ns
t _{BTRF}	TCK [BSCAN] rise/fall time	50	—	mV/ns
t _{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
t _{BTCODIS}	TAP controller falling edge of clock to valid disable	—	10	ns
t _{BTCOEN}	TAP controller falling edge of clock to valid enable	—	10	ns
t _{BTCRS}	BSCAN test capture register setup time	8	—	ns
t _{BTCRH}	BSCAN test capture register hold time	25	—	ns
t _{BUTCO}	BSCAN test update register, falling edge of clock to valid output	—	25	ns
t _{BTUODIS}	BSCAN test update register, falling edge of clock to valid disable	—	25	ns
t _{BTUPOEN}	BSCAN test update register, falling edge of clock to valid enable	_	25	ns









Pin Information Summary (Cont.)

		XP2-5			XP2-8			XP2-17		XP2-30		XP2-40					
Pin Type		132 csBGA	144 TQFP	208 PQFP	256 ftBGA	132 csBGA	144 TQFP	208 PQFP	256 ftBGA	208 PQFP	256 ftBGA	484 fpBGA	256 ftBGA	484 fpBGA	672 fpBGA	484 fpBGA	672 fpBGA
	Bank0	18	20	20	26	18	20	20	28	20	28	52	28	52	70	52	70
	Bank1	4	6	18	18	4	6	18	22	18	22	36	22	36	54	36	70
	Bank2	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
PCI capable I/Os	Bank3	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bank	Bank4	8	8	18	18	8	8	18	26	18	26	36	26	38	54	38	70
	Bank5	14	18	20	24	14	18	20	24	20	24	52	24	53	70	53	70
	Bank6	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	Bank7	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

1. Minimum requirement to implement a fully functional 8-bit wide DDR bus. Available DDR interface consists of at least 12 I/Os (1 DQS + 1 DQSB + 8 DQs + 1 DM + Bank VREF1).

Logic Signal Connections

Package pinout information can be found under "Data Sheets" on the LatticeXP2 product page of the Lattice website a www.latticesemi.com/products/fpga/xp2 and in the Lattice Diamond design software.

Thermal Management

Thermal management is recommended as part of any sound FPGA design methodology. To assess the thermal characteristics of a system, Lattice specifies a maximum allowable junction temperature in all device data sheets. Designers must complete a thermal analysis of their specific design to ensure that the device and package do not exceed the junction temperature limits. Refer to the Lattice <u>Thermal Management</u> document to find the device/ package specific thermal values.

For Further Information

- TN1139, Power Estimation and Management for LatticeXP2 Devices
- Power Calculator tool is included with the Lattice Diamond design tool or as a standalone download from www.latticesemi.com/products/designsoftware



Lead-Free Packaging

Commercial

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-5E-5MN132C	1.2V	-5	Lead-Free csBGA	132	COM	5
LFXP2-5E-6MN132C	1.2V	-6	Lead-Free csBGA	132	COM	5
LFXP2-5E-7MN132C	1.2V	-7	Lead-Free csBGA	132	COM	5
LFXP2-5E-5TN144C	1.2V	-5	Lead-Free TQFP	144	COM	5
LFXP2-5E-6TN144C	1.2V	-6	Lead-Free TQFP	144	COM	5
LFXP2-5E-7TN144C	1.2V	-7	Lead-Free TQFP	144	COM	5
LFXP2-5E-5QN208C	1.2V	-5	Lead-Free PQFP	208	COM	5
LFXP2-5E-6QN208C	1.2V	-6	Lead-Free PQFP	208	COM	5
LFXP2-5E-7QN208C	1.2V	-7	Lead-Free PQFP	208	COM	5
LFXP2-5E-5FTN256C	1.2V	-5	Lead-Free ftBGA	256	COM	5
LFXP2-5E-6FTN256C	1.2V	-6	Lead-Free ftBGA	256	COM	5
LFXP2-5E-7FTN256C	1.2V	-7	Lead-Free ftBGA	256	COM	5

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-8E-5MN132C	1.2V	-5	Lead-Free csBGA	132	COM	8
LFXP2-8E-6MN132C	1.2V	-6	Lead-Free csBGA	132	COM	8
LFXP2-8E-7MN132C	1.2V	-7	Lead-Free csBGA	132	COM	8
LFXP2-8E-5TN144C	1.2V	-5	Lead-Free TQFP	144	COM	8
LFXP2-8E-6TN144C	1.2V	-6	Lead-Free TQFP	144	COM	8
LFXP2-8E-7TN144C	1.2V	-7	Lead-Free TQFP	144	COM	8
LFXP2-8E-5QN208C	1.2V	-5	Lead-Free PQFP	208	COM	8
LFXP2-8E-6QN208C	1.2V	-6	Lead-Free PQFP	208	COM	8
LFXP2-8E-7QN208C	1.2V	-7	Lead-Free PQFP	208	COM	8
LFXP2-8E-5FTN256C	1.2V	-5	Lead-Free ftBGA	256	COM	8
LFXP2-8E-6FTN256C	1.2V	-6	Lead-Free ftBGA	256	COM	8
LFXP2-8E-7FTN256C	1.2V	-7	Lead-Free ftBGA	256	COM	8

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-17E-5QN208C	1.2V	-5	Lead-Free PQFP	208	COM	17
LFXP2-17E-6QN208C	1.2V	-6	Lead-Free PQFP	208	COM	17
LFXP2-17E-7QN208C	1.2V	-7	Lead-Free PQFP	208	COM	17
LFXP2-17E-5FTN256C	1.2V	-5	Lead-Free ftBGA	256	COM	17
LFXP2-17E-6FTN256C	1.2V	-6	Lead-Free ftBGA	256	COM	17
LFXP2-17E-7FTN256C	1.2V	-7	Lead-Free ftBGA	256	COM	17
LFXP2-17E-5FN484C	1.2V	-5	Lead-Free fpBGA	484	COM	17
LFXP2-17E-6FN484C	1.2V	-6	Lead-Free fpBGA	484	COM	17
LFXP2-17E-7FN484C	1.2V	-7	Lead-Free fpBGA	484	COM	17



Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-40E-5F484I	1.2V	-5	fpBGA	484	IND	40
LFXP2-40E-6F484I	1.2V	-6	fpBGA	484	IND	40
LFXP2-40E-5F672I	1.2V	-5	fpBGA	672	IND	40
LFXP2-40E-6F672I	1.2V	-6	fpBGA	672	IND	40



LatticeXP2 Family Data Sheet Supplemental Information

February 2012

Data Sheet DS1009

For Further Information

A variety of technical notes for the LatticeXP2 FPGA family are available on the Lattice Semiconductor web site at <u>www.latticesemi.com</u>.

- TN1136, LatticeXP2 sysIO Usage Guide
- TN1137, LatticeXP2 Memory Usage Guide
- TN1138, LatticeXP2 High Speed I/O Interface
- TN1126, LatticeXP2 sysCLOCK PLL Design and Usage Guide
- TN1139, Power Estimation and Management for LatticeXP2 Devices
- TN1140, LatticeXP2 sysDSP Usage Guide
- TN1141, LatticeXP2 sysCONFIG Usage Guide
- TN1142, LatticeXP2 Configuration Encryption and Security Usage Guide
- TN1087, Minimizing System Interruption During Configuration Using TransFR Technology
- TN1220, LatticeXP2 Dual Boot Feature
- TN1130, LatticeXP2 Soft Error Detection (SED) Usage Guide
- TN1143, LatticeXP2 Hardware Checklist

For further information on interface standards refer to the following websites:

- JEDEC Standards (LVTTL, LVCMOS, SSTL, HSTL): www.jedec.org
- PCI: <u>www.pcisig.com</u>

© 2012 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal. All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.